

TENTATIVE

TOSHIBA Transistor Silicon PNP·NPN Epitaxial Type (PCT Process)

HN3B02FU

Audio Frequency General Purpose Amplifier Applications

Unit: mm

Q1

• Excellent hFE linearity : hFE (IC = -0.1mA) / (IC = -2mA) = 0.95

(typ.)

Q2

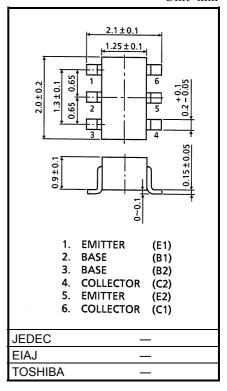
• Excellent hFE linearity : $h_{FE} (I_C = 0.1 \text{mA}) / (I_C = 2 \text{mA}) = 0.95 \text{ (typ.)}$

Q1 Maximum Ratings (Ta = 25°C)

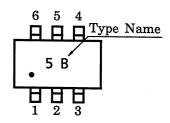
Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V _{CEO}	-50	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ic	-150	mA
Base current	ΙΒ	-50	mA

Q2 Maximum Ratings (Ta = 25°C)

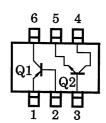
Characteristic	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	60	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	IC	150	mA
Base current	Ι _Β	30	mA



Marking



Equivalent Circuit (Top View)



Q1 Q2 Common Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector power dissipation	P _C (*)	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	−55~125	°C

^{*:} Total rating

Q1 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	_	$V_{CB} = -50V, I_E = 0$	_	_	-0.1	μA
Emitter cut-off current	I _{EBO}	_	$V_{EB} = -5V$, $I_C = 0$	_	_	-0.1	μA
DC current gain	h _{FE}	_	$V_{CE} = -6V, I_{C} = -2mA$	120	_	400	_
Collector-emitter saturation voltage	V _{CE (sat)}	_	I _C = -100mA, I _B = -10mA	_	-0.1	-0.3	٧
Transition frequency	f _T	_	$V_{CE} = -10V, I_{C} = -1mA$	_	120	_	MHz
Collector output capacitance	C _{ob}	_	$V_{CB} = -10V$, $I_E = 0$, $f = 1MH_z$	_	4	_	pF

Q2 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	_	V _{CB} = 60V, I _E = 0	_	_	0.1	μA
Emitter cut-off current	I _{EBO}	_	$V_{EB} = 5V, I_C = 0$	_	_	0.1	μΑ
DC current gain	h _{FE}	_	V _{CE} = 6V, I _C = 2mA	120	_	400	_
Collector-emitter saturation voltage	V _{CE (sat)}	_	I _C = 100mA, I _B = 10mA	_	0.1	0.25	V
Transition frequency	f _T	_	V _{CE} = 10V, I _C = 1mA	_	150	_	MH_z
Collector output capacitance	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MH _z	_	2	_	pF

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